

RD 2.0S...47S	Z-Di	=RD 2.0M...47M: 0,2W	71a(1,7mm)	-	
RD 2.7SL...39SL	Z-Di	=RD 4.7JS...39JS: 0,2W	71a(1,7mm)	-	
RD 2.0UH...4.7UH	Z-Di	=RD 2.0HS...4.7HS: SMD, 0,15W	71a(1,3mm)	-	
RD 4.7UJ...39UJ	Z-Di	=RD 4.7S...39S: SMD, 0,15W	71a(1,3mm)	-	
RD 2.0UM...39UM	Z-Di	=RD 2.0M...39M: 0,15W	71a(1,3mm)	-	
RD 6.2 Z	Z-Di	SMD, Z, Dual, Tuner-Di, 5,9...6,5V	35n	-	
RD B-50	Ge-P		2a	(AC 188 K)	3a
RF-1(A,B,Z)	Si-Di	GI, S, 200...800V, 0,6A, <400ns	31a	BA 159	31a
RF 2,7...200	Z-Di	=BZX 46 C2V7...C200: 0,4W	31a	Z-Diode ...V	31a
RF 03 E14	Se-Di			-	
RF 400	C-Di	FM/VHF-AFC	31a	-	
RF 401	C-Di	FM/VHF-AFC	31a	-	
RF 500	C-Di	Dual, FM-Tuning	7e	-	
RF 2001	Si-Di	GI, Uni, 50V, 2A	31a	BY 255	31a
RF 2002	Si-Di	=RF 2001: 100V	31a	BY 255	31a
RF 2003	Si-Di	=RF 2001: 200V	31a	BY 255	31a
RF 2004	Si-Di	=RF 2001: 400V	31a	BY 255	31a
RF 2005	Si-Di	=RF 2001: 600V	31a	BY 255	31a
RF 2006	Si-Di	=RF 2001: 800V	31a	BY 255	31a
RF 2007	Si-Di	=RF 2001: 1000V	31a	BY 255	31a
RFP 15 N12	MOS-N-FET-e	V-MOS, 120V, 15A, 75W, <0,15Ω(7,5A)	17p	-	
RFP 15 N15	MOS-N-FET-e	=RFP 15N12: 150V	17p	-	
RFP 18 N08	MOS-N-FET-e	V-MOS, 80V, 18A, 75W, <0,1Ω(9A)	17p	-	
RFP 18 N10	MOS-N-FET-e	=RFP 18N08: 100V	17p	-	
RG 1 A...M	Si-Di	GI, S, 50...1000V, 1A, <150...500ns	31a	BYD 33 M	31a
RG 1C	Si-Di	GI, S, 1000V, 0,7A, 100ns	31a	BA 159	31a
RG 2 A...M	Si-Di	GI, S, 50...1000V, 2A, <150...500ns	31a	BYW 95 C(600V)	31a
				BYW 96E(1000V)	31a
RG 2 A2	Si-Di	TV-Damper-Di, 1300V, 0,5A, 100ns	31a	(BY 228)	31a
RG 2(A,Y,Z)	Si-Di	GI, S, 70...600V, 0,5A, 100ns	31a	BA 159	31a
RG 3 A...M	Si-Di	GI, S, 50...1000V, 3A, <150...500ns	31a	BYW 95 C(600V)	31a
				BYW 96E(1000V)	31a
RG 4 A...M	Si-Di	GI, S, 50...1000V, 3A, <150...500ns	31a	BYW 95 C(600V)	31a
				BYW 96E(1000V)	31a
RG 4	Si-Di	GI, S, 400V, 3A, 100ns	31a	BYW 95 C	31a
RG 4 A	Si-Di	GI, S, 600V, 2A, 100ns	31a	BYW 95 C	31a
RG 4 C	Si-Di	GI, S, 1000V, 2A, 100ns	31a	BYW 96 E	31a
RG 4 Y	Si-Di	GI, S, 70V, 3,5A, 100ns	31a	BYW 95 C	31a
RG 4 Z	Si-Di	GI, S, 200V, 1,5A, 100ns	31a	BYW 95 C	31a
RG 10	Si-Di	GI, S, 400V, 1,2A, 100ns	31a	BYD 33 M	31a
RG 10 A	Si-Di	GI, S, 600V, 1A, 100ns	31a	BYD 33 M	31a
RG 10 Y	Si-Di	GI, S, 70V, 1,5A, 100ns	31a	BYD 33 M	31a
RGP 01-10...-20	Si-Di	GI, S, 1000...2000V, 0,1A, <300ns	31a	BY 203/20	31a
RGP 10 A...M	Si-Di	GI, S, 50...1000V, 1A, <150...500ns	31a	BYD 33 M	31a
RGP 15 A...M	Si-Di	GI, S, 50...1000V, 1,5A, <150...500ns	31a	BYD 33 M	31a
RGP 15-10...-20	Si-Di	GI, S, 1000...2000V, 1A, <250ns	31a	BY 228(1600V)	31a
RGP 20 A...J	Si-Di	GI, S, 50...600V, 2A, <150...250ns	31a	BYW 95 C	31a
RGP 25 A...M	Si-Di	GI, S, 50...1000V, 2,5A, <150...500ns	31a	BYW 95 C(600V)	31a
				BYW 96 E	31a
RG 30 A...M	Si-Di	GI, S, 50...1000V, 3A, <150...500ns	31a	RGP 30 M	31a
		RGP 30MS = 900V		BYW 96 E	31a
RGP 50 A...M	Si-Di	GI, S, 50...1000V, 5A, <150...500ns	31a	BY 500/800	31a
RGP 80 A...M	Si-Di	GI/S-L, 50...1000V, 8A, <150...500ns	17k	BY 359/1500	17k
RGP 5005	Si-Di	GI, S, 50V, 0,5A, <750ns	31a	BYD 33 M	31a
RGP 5010	Si-Di	=RGP 5005: 100V	31a	BYD 33 M	31a